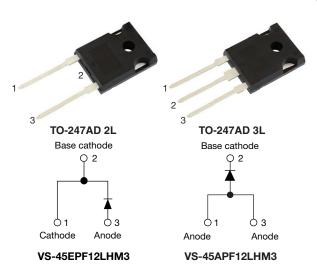
VS-45EPF12LHM3, VS-45APF12LHM3

Vishay Semiconductors

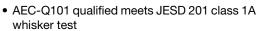
Fast Soft Recovery Rectifier Diode, 45 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	45 A				
V_{R}	1200 V				
V _F at I _F	1.44 V				
I _{FSM}	550 A				
t _{rr}	95 ns				
T _J max.	150 °C				
Package	TO-247AD 2L, TO-247AD 3L				
Circuit configuration	Single				
Snap factor	0.5				

FEATURES

- · Very low forward voltage drop
- · Glass passivated pellet chip junction





- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage, and short reverse recovery time.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Sinusoidal waveform	45	A			
V _{RRM}		1200	V			
I _{FSM}		550	A			
V _F	20 A, T _J = 25 °C	1.22	V			
t _{rr}	1 A, 100 A/μs	95	ns			
T _J		-40 to +150	°C			

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-45EPF12LHM3	1200	1300	10			
VS-45APF12LHM3	1200	1300	10			



VS-45EPF12LHM3, VS-45APF12LHM3

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 97 °C, 180° conduction half sine wave	45			
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	462	Α		
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	550			
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	1069	A ² s		
waximum i=t for fusing	1-1	10 ms sine pulse, no voltage reapplied	1513	A-s		
Maximum l ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	15 125	A ² √s		

ELECTRICAL SPECIFICATIONS					
PARAMETER	VALUES	UNITS			
Maximum forward voltage drop	V_{FM}	45 A, T _J = 25 °C		1.44	V
Forward slope resistance	r _t	T.ı = 150 °C		6.82	mΩ
Threshold voltage	V _{F(TO)}	1) = 150 C		0.94	V
Maximum reverse leakage current	1	$T_J = 25 ^{\circ}\text{C}$ $V_B = \text{rated } V_{BBM}$		0.1	mA
waximum reverse leakage current	I _{RM}	T _J = 150 °C	VR = rated VRRM	10	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	I⊏ at 40 A _{ak}	450	ns	I _{FM} +
Reverse recovery current	Irr	I _F at 40 A _{pk} 25 A/µs	6	Α	$t_a \mid t_b$
Reverse recovery charge	Q _{rr}	25 °C	1.8	μC	dir/ dt Q _{rr}
Snap factor	S	Typical	0.5		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, unction to case		R_{thJC}	DC operation	0.4	
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W
Typical thermal resistand case to heatsink	Typical thermal resistance, case to heatsink		Mounting surface, smooth, and greased	0.25	
Approximate weight				6	g
Approximate weight				0.21	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
Mounting torque —	maximum			12 (10)	(lbf ⋅ in)
Marking davisa	Madis de la		Case style TO-247AD 2L	45EPF	12LH
Marking device			Case style TO-247AD 3L	45APF	12LH

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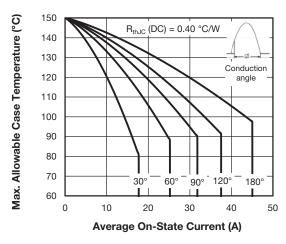


Fig. 1 - Current Rating Characteristics

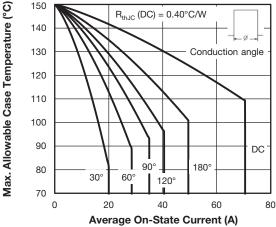


Fig. 2 - Current Rating Characteristics

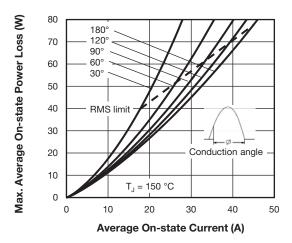


Fig. 3 - Forward Power Loss Characteristics

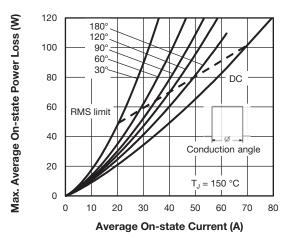


Fig. 4 - Forward Power Loss Characteristics

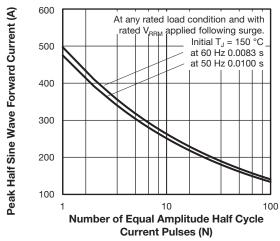


Fig. 5 - Maximum Non-Repetitive Surge Current

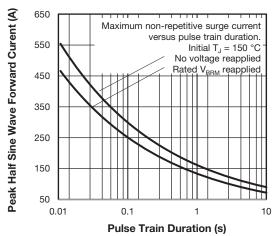


Fig. 6 - Maximum Non-Repetitive Surge Current

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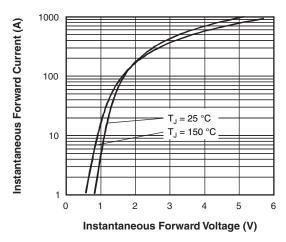


Fig. 7 - Forward Voltage Drop Characteristics

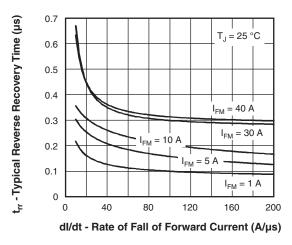


Fig. 8 - Thermal Impedance ZthJC Characteristics

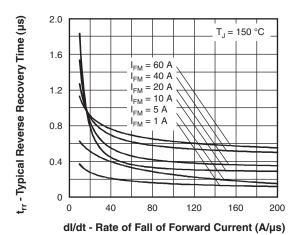


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

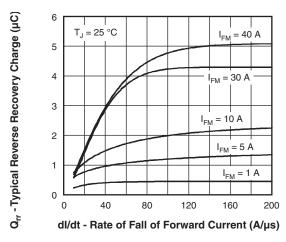


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

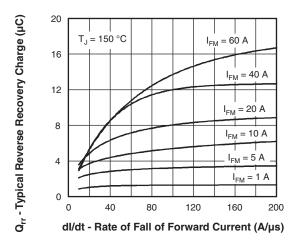


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

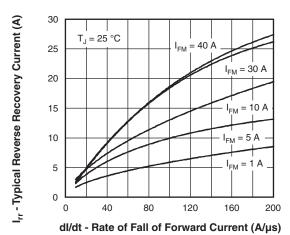


Fig. 12 - Recovery Current Characteristics, $T_J = 25 \, ^{\circ}\text{C}$

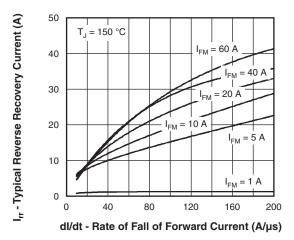


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

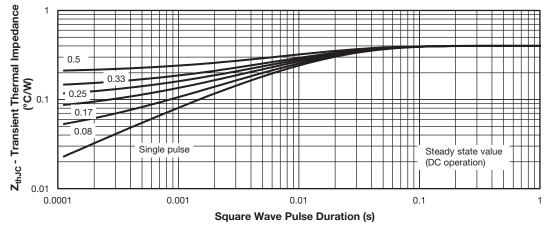


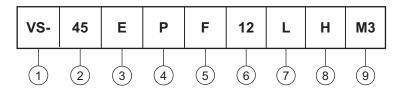
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-45EPF12LHM3, VS-45APF12LHM3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (45 = 45 A)

3 - Circuit configuration:

E = single, 2 pins

A = single, 3 pins

4 - Package:

P = TO-247AD

5 - Type of silicon:

F = fast recovery rectifier

7 - L = long leads

8 - H = AEC-Q101 qualified

9 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-45EPF12LHM3	25	500	Antistatic plastic tubes			
VS-45APF12LHM3	25	500	Antistatic plastic tubes			

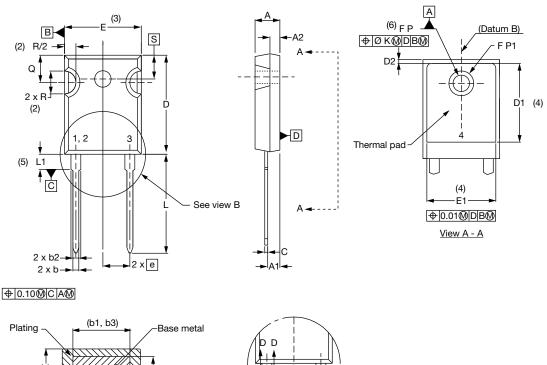
LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536			
Dimensions ——	TO-247AD 3L	www.vishay.com/doc?95626			
Dort marking information	TO-247AD 2L	www.vishay.com/doc?95648			
Part marking information –	TO-247AD 3L	www.vishav.com/doc?95007			



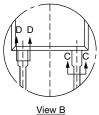
Vishay Semiconductors

TO-247AD 2L

DIMENSIONS in millimeters and inches



MILLIMETER	28	INCHES	
1	- (b, b2) - (c)	4)	
(c)		l _{c1}	



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.254		0.0	10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	
		<u> </u>	<u> </u>	<u> </u>	·

Notes

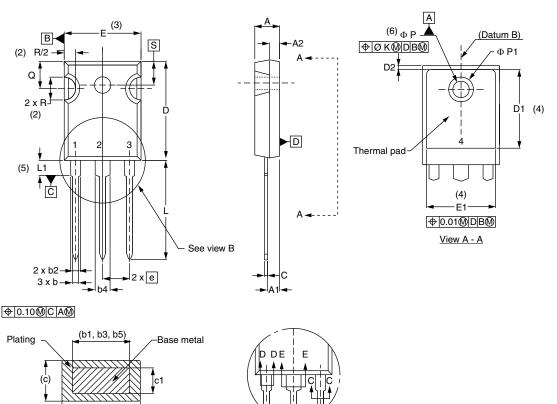
- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



Vishay Semiconductors

TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

Section C - C, D - D, E - E

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	=.	0.53	-	
е	5.46 BSC		0.215 BSC		
ØK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
	•			•	

Notes

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- (2) Contour of slot optional
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